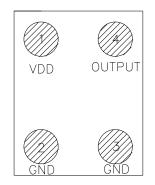
WMM7037ATTS0

Top port analog silicon Microphone

Descriptions

The WMM7037ATTS0 is a miniature, high performance, low power, top port silicon microphone. The WMM7037ATTS0 consists of an acoustic sensor, a low noise input buffer, and an output amplifier. These devices are suitable for protable electronic devices where excellent wideband audio performance and RF immunity are required applications.

The WMM7037ATTS0 is manufactured in a compact 3.76mm*2.95mm*1.10mm, 4-pin LGA package.



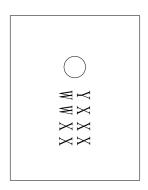
Pin configuration (Bottom view)

Features

- Matched Sensitivity
- Low current
- Small package
- MaxRF protection
- Ultra-Stable Performance
- Standard SMD Reflow
- Omnidirectional

Applications

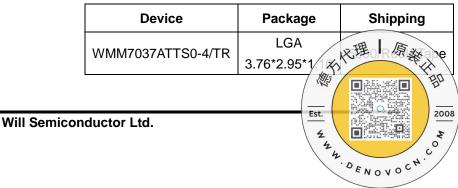
- Cellphones
- Smart phones
- Laptop computers
- Smart speakers
- Digital still cameras
- Portable music recorders



Marking (Top view)

Y = Year code WW = Week code X X = Data code

Order information



Absolute maximum ratings

Parameter	Absolute Maximum Rating	Units
Supply voltage	4.2	V
Operation temperature range	-40~85	°C
Storage temperature range	-40 ~100	°C

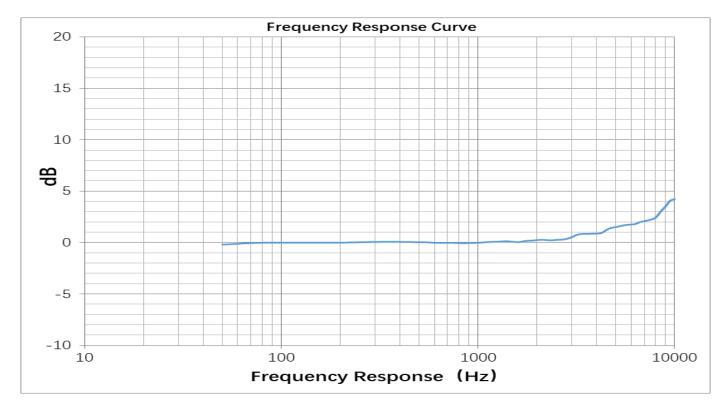
Stresses exceeding these "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only. Functional operation at these or any other conditions beyond those indicated under "Acoustic & Electrical Specifications" is not implied. Exposure beyond those indicated under "Acoustic & Electrical Specifications" for extended periods may affect device reliability.

Acoustic & Electrical Specifications

Test condition: +25±2°C, 60%~70%RH, 86~106Kpa, Vdd=2V, no load, unless otherwise specified

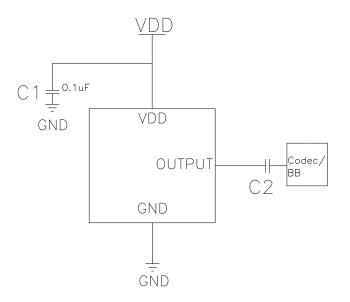
Parameter	Symbol	Condition	Min.	Nom.	Max.	Unit
Sensitivity	S	f=1KHz, Pin=1Pa, 0dB=1V/Pa	-43	-42	-41	dB
Operating Voltage	Vdd		1.6	2	3.6	V
Directivity			Omi	ni-directio	nal	
Polarity		Sound pressure increase	Output voltage increase			
Output Impedance	Zout	f=1KHz	-	-	300	Ω
Current Consumption ¹	I	1.6 V to 3.6V	-	120	200	μA
S/N Ratio	S/N	A-Weighted	-	58		dBA
Total Harmonic Distortion	THD	94dBSPL@1KHz	-	0.2	0.5	%
Acoustic Overload Point	AOP	THD 10%@1KHz	-	130	-	dBSPL
Power Supply Rejection	PSR	100mVpp Square-wave @217Hz, A-weighted	-	-105	-	dB
Power Supply Rejection Ratio	PSRR	200mVpp Sinewave @1KHz	-	80	-	dB
DC output	VDC		-	0.85	-	V





Frequency Response Curve

Application Information



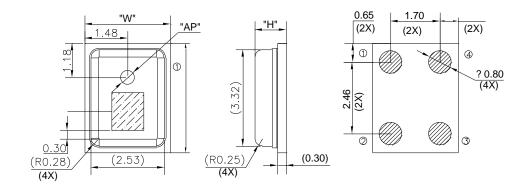
Note:

- All GND pins must be connected to ground.
- Capacitors near the microphone should not contain Class 2 dielectrics.



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Mechanical Specification



Item	Dimension	Tolerance
Length(L)	3.76	±0.10
Width(W)	2.95	±0.10
Height(H)	1.10	±0.10
Acoustic Port (AP)	Ø0.50	±0.05

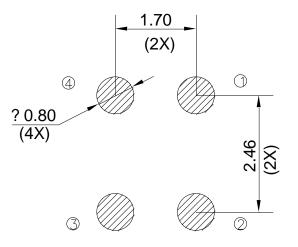
Pin#	Pin Name	Description
1	VDD	Power Supply
2	GND	GND
3	GND	GND
4	OUTPUT	Output Signal

Notes:

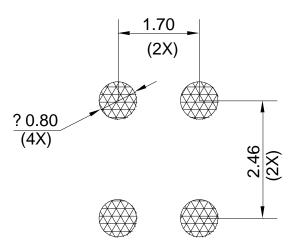
- Dimensions are in millimeters unless otherwise specified.
- Tolerance is ±0.10mm unless otherwise specified.



Example Land Pattern



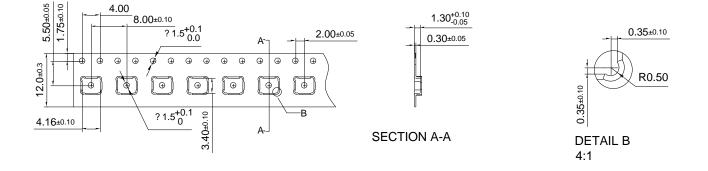
Example Solder Stencil Pattern



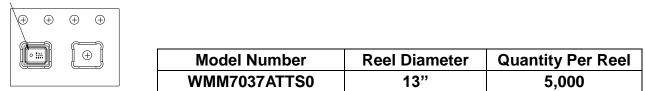


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Packaging & Marking Detail



PIN1

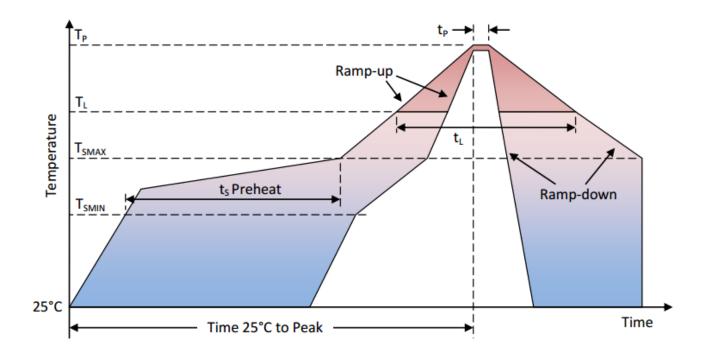


Notes:

- Dimensions are in millimeters unless otherwise specified.
- Vacuum pickup only in the pick area indicated in Mechanical Specifications.
- Tape & reel per EIA-481.
- Labels applied directly to reel and external package.



Referenced Reflow Profile



Profile Feature	Pb-Free
Average Ramp-up rate (TSMAX to TP)	3°C/second max.
Preheat • Temperature Min (Tsmin) • Temperature Max (Tsmax) • Time (Tsmin to Tsmax) (ts)	150°C 200°C 60-180 seconds
Time maintained above: • Temperature (TL) • Time (tL)	217°C 60-150 seconds
Peak Temperature (TP)	260°C
Time within 5°C of actual Peak Temperature (tP)	20-40 seconds
Ramp-down rate (TP to TSMAX)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max

Note:

All temperatures refer to topside of the package, measured on the package body surface.



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Additional Notes

- (A) Maximum of 3 reflow cycles is recommended.
- (B) In order to minimize device damage:
 - Do not board wash or clean after the reflow process.
 - Do not brush board with or without solvents after the reflow process.
 - Do not directly expose to ultrasonic processing, welding, or cleaning.
 - Do not insert any object in port hole of device at any time.
 - Do not apply over 30 psi of air pressure into the port hole.
 - Do not pull a vacuum over port hole of the microphone.

• Do not apply a vacuum when repacking into sealed bags at a rate faster than 0.5 atm/sec.

Materials Statement

Meets the requirements of the European RoHS and Halogen-Free.

Test	Description
Thermal Shock	100 cycles air-to-air thermal shock from -40°C to +125°C with 15 minute soaks.
High Temperature Storage	1000 hours at +105°C environment
Low Temperature Storage	1000 hours at -40°C environment
High Temperature Bias	1000 hours at +105°C under bias.
Low Temperature Bias	1000 hours at -40°C under bias.
Temperature / Humidity Bias	1000 hours at +85°C /85% R.H.
Vibration	4 cycles of 20 to 2,000 Hz sinusoidal sweep with 20g peak acceleration lasting 12 minutes in X, Y, and Z directions.
ESD-HBM	3 discharges of ±2 kV direct contact to I/O pins.
ESD-LID/GND	3 discharges of ±8 kV direct contact to lid while unit is grounded.
ESD-MM	3 discharges of ±200V direct contact to I/O pins.
Reflow	5 reflow cycles with peak temperature of +260°C
Mechanical Shock	3 pulses of 10,000g in the X, Y, and Z direction
Drop Test 1.0cm steel plate 18 times from 1.5 meter height.	

Reliability Specifications

Note:

Tre K理 原義 After reliability tests are performed, the sensitivity of the microphones shall not deviate more from its initial value.